

# N-Channel 40V (D-S) Power MOSFET

### **Features**

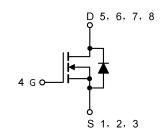
- 100% Avalanche Tested
- Extremely Low Losses with Low FOM Rdson\*Qg
- Halogen Free, Pb-Free
- RoHS Compliant



### **PDFN5060**

## **Applications**

- DC-DC
- Motors, lamps
- Power switching



Absolute Maximum Ratings (T <sub>J</sub> =25°C unless otherwise noted)						
Parameter	Symbol	Value	Unit			
Drain Source Voltage		V <sub>DS</sub>	40	V		
Gate Source Voltage		$V_{GS}$	±20	V		
Drain Current, Continuous	T <sub>C</sub> =25°C	1	180	A		
V <sub>GS</sub> =10V(Note 1)	T <sub>C</sub> =100°C	l <sub>D</sub>	107			
Drain Current, Pulsed (Note 2)		I <sub>DM</sub>	720	А		
Power Dissipation(Note 3)	T <sub>C</sub> =25°C	P <sub>D</sub>	100	W		
Operating Junction/ Storage Tempe	rature Range	T <sub>J</sub> / T <sub>STG</sub> -55 to +150		°C		

Note 1: Calculated continuous current based on maximum allowable junction temperature.

Note 2: Repetitive rating; pulse width limited by max. junction temperature.

Thermal Characteristics						
Parameter	Symbol	Max	Unit			
Thermal Resistance Junction to Case(Note 3)	R <sub>thJC</sub>	1.25	°C/W			

Note 3: The power dissipation PD is based on max. junction temperature, using junction-to-case thermal resistance.



Electrical Characteristics (T <sub>J</sub> =25°C unless otherwise noted)						
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	40			V
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =40V, V <sub>GS</sub> =0V			1.0	uA
Gate Threshold Voltage	V <sub>GS(TH)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>DS</sub> =250uA	2		4	V
Gate Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V			±100	nA
Drain-Source On-state Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =40A		1.7	2.4	mΩ
Total Gate Charge	Qg	L = 20 A		130		
Gate-Source Charge	Q <sub>gs</sub>	I <sub>D</sub> = 20A, V <sub>DS</sub> =20V,		23		nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> = 10V		36		
Turn-on Delay Time	t <sub>d(on)</sub>			35		
Turn-on Rise Time	t <sub>r</sub>	$V_{GS}$ =10V, $V_{DD}$ =20V, $R_{GEN}$ =3.6 $\Omega$ , $R_{L}$ =1 $\Omega$		34		
Turn-off Delay Time	t <sub>d(off)</sub>			67		ns
Turn-off Fall Time	t <sub>f</sub>			21		
Input Capacitance	C <sub>iss</sub>			9792		
Output Capacitance	C <sub>oss</sub>	V <sub>GS=</sub> 0V, V <sub>DS</sub> =30V, f=1MHz		660		pF
Reverse Transfer Capacitance	C <sub>rss</sub>			524		

Reverse Diode Characteristics (T <sub>J</sub> =25°C unless otherwise noted)						
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Continuous Source Current (Body Diode)	Is	T <sub>C</sub> =25°C			10	_
Pulsed Source Current (Body Diode)	I <sub>SM</sub>				40	Α
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =3A, V <sub>GS</sub> =0V			1.2	V
Reverse Recovery Time	T <sub>rr</sub>	L_ =10A_di/dt = 100 A/ua		20		ns
Reverse Recovery Charge	Qrr	I <sub>F</sub> =10A, di/dt = 100 A/μs		20		nC



## Typical Characteristics Curves (T<sub>J</sub> = 25°C unless otherwise noted)

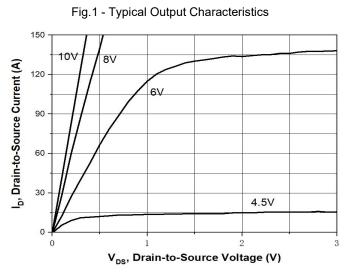


Fig.3 - RDS(on) vs. Junction Temperature

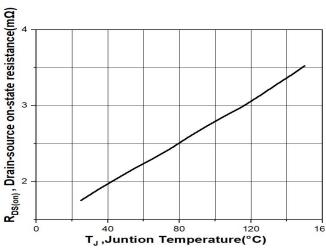


Fig.5 - Capacitance

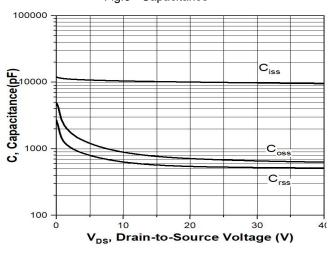


Fig.2 - Drain-to-Source Breakdown Voltage vs. Junction Temperature

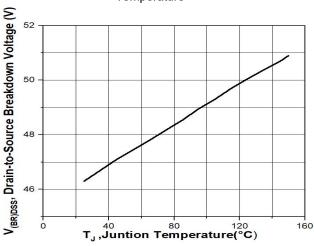


Fig.4 - Vth vs. Junction Temperature

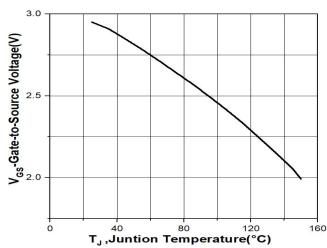
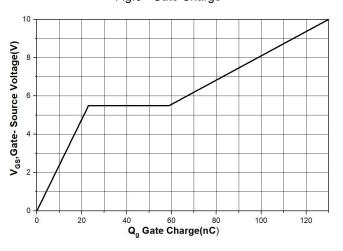


Fig.6 - Gate Charge





# **Typical Characteristics Curves** (T<sub>J</sub> = 25°C unless otherwise noted)

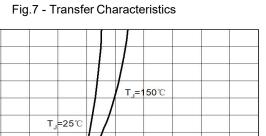
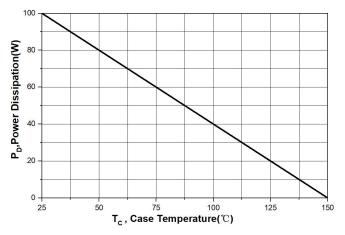


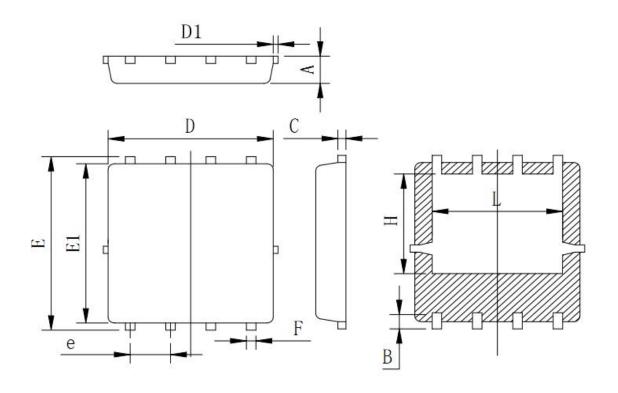
Fig.8 - Power Dissipation





# Package Outline Dimensions (Unit: millimeters)

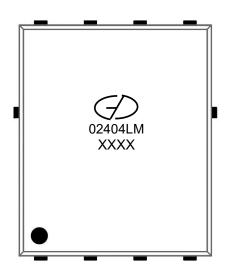
# **PDFN5060**



Symbol	Min	Тур	Max
A	0.90	0.95	1.00
В	0.48	0.58	0.68
С	0.20	0.254	0.30
D	5.00	5.20	5.40
D1			0.15
Е	5.90	6.05	6.20
El	5.40	5.55	5.70
е	1.22	1.27	1.32
F	0.25	0.30	0.35
Н	3.27	3.47	3.67
L	3.80	4.00	4.20



# **Marking Outline**



Part Name: GMN02404LM

1. Logo Mark:

2. P/N Mark: 02404LM

3. Date Code: XXXX

4. Pin 1#: ●



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